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October 2016

FOD420, FOD4208, FOD4216, FOD4218 6-Pin DIP High dv/dt Random Phase Triac Drivers

Features

- · 300 mA On-State Current
- · High Blocking Voltage
 - 600 V (FOD420, FOD4216)
 - 800 V (FOD4208, FOD4218)
- · High Trigger Sensitivity
 - 1.3 mA (FOD4216, FOD4218)
 - 2 mA (FOD420, FOD4208)
- High Static dv/dt (10,000 V/µs)
- · Safety and Regulatory Approvals:
 - UL1577, 5,000 VAC_{RMS} for 1 Minute
 - DIN-EN/IEC60747-5-5

Applications

- Solid-State Relays
- Industrial Controls
- Lighting Controls
- Static Power Switches
- · AC Motor Starters

Description

The FOD420, FOD4208, FOD4216 and FOD4218 devices consist of an infrared emitting diode coupled to a hybrid random phase triac formed with two inverse parallel SCRs which form the triac function capable of driving discrete triacs. The FOD4216 and FOD4218 utilize a high efficiency infrared emitting diode which offers an improved trigger sensitivity. These devices are housed in a standard 6-pin dual in-line (DIP) package.

Functional Schematic

ANODE 1 CATHODE 2 N/C 3 *DO NOT CONNECT

Package Outlines

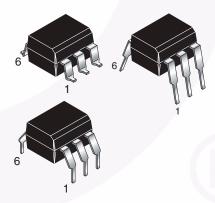


Figure 2. Package Outlines

Figure 1. Schematic

(TRIAC SUBSTRATE)

Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Parameter	Characteristics	
Installation Classifications per DIN VDE	< 150 V _{RMS}	I–IV
0110/1.89 Table 1, For Rated Mains Voltage	< 300 V _{RMS}	I–IV
Climatic Classification		55/100/21
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V	Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with $t_m = 10 \text{ s}$, Partial Discharge < 5 pC	1360	V _{peak}
V _{PR}	Input-to-Output Test Voltage, Method B, V _{IORM} x 1.875 = V _{PR} , 100% Production Test with t _m = 1 s, Partial Discharge < 5 pC	1594	V _{peak}
V _{IORM}	Maximum Working Insulation Voltage	850	V _{peak}
V _{IOTM}	Highest Allowable Over-Voltage	6000	V _{peak}
	External Creepage	≥ 7	mm
	External Clearance	≥ 7	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥ 0.4	mm
T _S	Case Temperature ⁽¹⁾	175	°C
I _{S,INPUT}	Input Current ⁽¹⁾	400	mA
P _{S,OUTPUT}	Output Power ⁽¹⁾	700	mW
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V ⁽¹⁾	> 10 ⁹	Ω

Note:

1. Safety limit values – maximum values allowed in the event of a failure.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A = 25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Device	Value	Unit	
T _{STG}	Storage Temperature	All	-55 to +150	°C	
T _{OPR}	Operating Temperature	All	-55 to +100	°C	
T _J	Junction Temperature	All	-55 to +125	°C	
T _{SOL}	Lead Solder Temperature	All	260 for 10 sec	°C	
В	Total Device Power Dissipation @ 25°C	All	500	mW	
P _{D(TOTAL)}	Derate Above 25°C	All	6.6	mW/°C	
EMITTER					
I _F	Continuous Forward Current	All	30	mA	
V _R	Reverse Voltage	All	6	V	
Б	Total Power Dissipation 25°C Ambient	All	50	mW	
P _{D(EMITTER)}	Derate Above 25°C	All	0.71	mW/°C	
DETECTOR					
	Off Chata Custout Tamainal Valtage	FOD420, FOD4216	600		
V_{DRM}	Off-State Output Terminal Voltage	FOD4208, FOD4218	800	- V	
I _{TSM}	Peak Non-Repetitive Surge Current (single cycle 60 Hz sine wave)	All	3	Α	
I _{TM}	Peak On-State Current	All	300	mA	
В	Total Power Dissipation @ 25°C Ambient	All	450	mW	
P _{D(DETECTOR)}	Derate Above 25°C	All	5.9	mW/°C	

Electrical Characteristics

 $T_A = 25$ °C unless otherwise specified.

Individual Component Characteristics

Symbol	Parameter	Test Cor	nditions	Device	Min.	Тур.	Max.	Unit
EMITTER	ĺ	- 1		•	•			
V _F	Input Forward Voltage	I _F = 20 mA		All		1.28	1.50	V
I _R	Reverse Leakage Current	V _R = 6 V		All		0.01	10	μA
DETECT	OR							
D (D140)	Peak Blocking Current,	I _F = 0,	V _D = 600 V	FOD420, FOD4216		3	100	μА
	Either Direction	$T_A = 100^{\circ}C^{(2)}$	V _D = 800 V	FOD4208, FOD4218				
	Deverage Comment	T _A = 100°C	V _D = 600 V	FOD420, FOD4216		3	100	μA
I _{R(RMS)} Reverse Current	Reverse Current		V _D = 800 V	FOD4208, FOD4218				
dv/dt	Critical Rate of Rise of Off-State Voltage	I _F = 0 A ⁽³⁾ (Figure 14)	$V_D = V_{DRM}$	All	10,000			V/µs

Notes:

- 2. Test voltage must be applied within dv/dt rating.
- 3. This is static dv/dt. See Figure 14 for test circuit. Commutating dv/dt is a function of the load-driving thyristor(s) only.

Electrical Characteristics (Continued)

 $T_A = 25$ °C unless otherwise specified.

Transfer Characteristics

Symbol	Parameter	Te	est Conditions	Device	Min.	Тур.	Max.	Unit					
le	I _{FT} LED Trigger Current		Main Terminal Voltage = 5 V ⁽⁴⁾			0.75 2.0	mA						
'FT	LLD Higger Culterit	Main Terminal Vollage = 5 VV		FOD4216, FOD4218		0.75 1.3	ША						
V_{TM}	Peak On-State Voltage, Either Direction	I _{TM} = 300 mA	peak, I _F = Rated I _{FT}	All		2.2	3	٧					
Ι _Η	Holding Current, Either Direction	V _T = 3 V		All		200	500	μΑ					
ΙL	Latching Current	V _T = 2.2 V		All		5		mA					
t _{ON}	Turn-On Time		V _{RM} = V _{DM} = 424 VAC	FOD420, FOD4216, FOD4218		60		μs					
		PF = 1.0, I _T = 300 mA	$V_{RM} = V_{DM} = 565 \text{ VAC}$	FOD4208	1								
t _{OFF}	Turn-Off Time		I _T = 300 mA	I _T = 300 mA	I _T = 300 mA	I _T = 300 mA	I _T = 300 mA	I _T = 300 mA	I _T = 300 mA	V _{RM} = V _{DM} = 424 VAC	FOD420, FOD4216, FOD4218	52	
			$V_{RM} = V_{DM} = 565 \text{ VAC}$	FOD4208									
dv/dt _C	Critical Rate of Rise of Voltage at Current Com- mutation	$V_D = 230 V_{RMS},$ $I_D = 300 \text{ mA}_{PK}$		All		10		V/µs					
di/dt _C	Critical Rate of Rise of On-State Current Commutation	V _D = 230 V _{RMS} , I _D = 300 mA _{PK}		All		9		A/ms					
dv(_{IO})/dt	Critical Rate of Rise of Coupled Input/Output Voltage	I _T = 0 A, V _{RM =} V _{DM} = 424 VAC		All	10,000			V/µs					

Note:

4. All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT}. Therefore, recommended operating I_F lies between max I_{FT} (2 mA for FOD420 and FOD4208 and 1.3 mA for FOD4216 and FOD4218) and the absolute max I_F (30 mA).

Isolation Characteristics

Symbol	Parameter	Test Conditions	Device	Min.	Тур.	Max.	Unit
V _{ISO}	Steady State Isolation	f = 60 Hz. t = 1 Minute ⁽⁵⁾	All	5,000			\/AC
	Voltage	1 – 60 Hz, t – 1 Williate	All	5,000	. 2		VAC _{RMS}

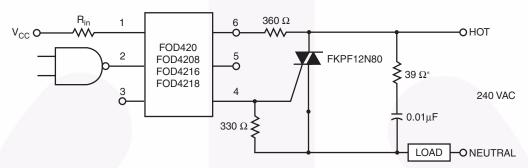
Note:

5. Isolation voltage, V_{ISO} , is an internal device dielectric breakdown rating. For this test, pins 1, 2 and 3 are common, and pins 4, 5 and 6 are common. 5,000 VAC_{RMS} for 1 minute duration is equivalent to 6,000 VAC_{RMS} for 1 second duration.

Typical Application

Figure 3 shows a typical circuit for when hot line switch-ing is required. In this circuit the "hot" side of the line is switched and the load connected to the cold or neutral side. The load may be connected to either the neutral or hot line.

Rin is calculated so that IF is equal to the rated IFT of the part, 2 mA for FOD420 and FOD4208, 1.3 mA for FOD4216 and FOD4218. The 39 Ω resistor and 0.01 μ F capacitor are for snubbing of the triac and may or may not be necessary depending upon the particular triac and load use.



* For highly inductive loads (power factor < 0.5), change this value to 360 ohms.

Figure 3. Hot-Line Switching Application Circuit

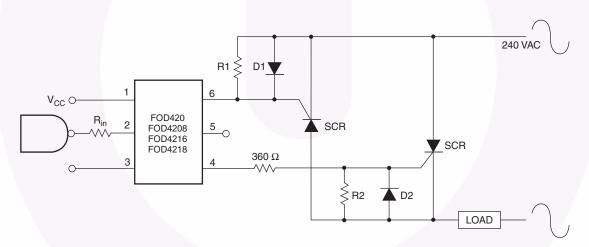


Figure 4. Inverse-Parallel SCR Driver Circuit

Suggested method of firing two, back-to-back SCR's with a Fairchild triac driver. Diodes can be 1N4001; resistors, R1 and R2, are optional 330 Ω .

Note: This optoisolator should not be used to drive a load directly. It is intended to be a discrete triac driver device only.

Typical Performance Characteristics IFT - NORMALIZED LED TRIGGER CURRENT V_{AK} = 5.0 V Normalized to T_A = 25°C V_F – FORWARD VOLTAGE (V) 1.4 -55°C 1.2 25°C 1.0 1.0 0.8 0.8 0.6 20 40 60 10 -60 100 IF - FORWARD CURRENT (mA) AMBIENT TEMPERATURE (°C) Figure 5. Forward Voltage Figure 6. Normalized LED Trigger Current (V_F) vs. Forward Current (I_F) (IFT) vs. Ambient Temperature (TA) 100 10000 $t_D = t(I_F/I_{FT\ 25^{\circ}C})$ $V_D = 400\ V_{P-P}$ $F = 60\ Hz$ If(pk) - PEAK LED CURRENT (mA) **Duty Factor** t_D – DELAY TIME (µs) 0.01 1000 0.02 10 0.2 100 10 -6 10-6 10-3 10-2 10-1 100 I_{FT}/I_F – NORMALIZED I_F (mA) t - LED PULSE DURATION (s) Figure 8. Trigger Delay Time Figure 7. Peak LED Current vs. Duty Factor, Tau 1000 1.7 IFTH(PW)/IFTH(DC) - NORMALIZED IFTH V_L = 250 V_{P-P} F = 60 Hz 1.6 I_{TM} – ON-STATE CURRENT (mA) Normalized to DC 1.5 100 1.4 1.3 T_A = 100°C 1.2 T_A = 25°C 10 1.1 1.0 0.9 0 200 400 600 800 1000 0 3 P_W – PULSE WIDTH (µs) V_{TM} – ON-STATE VOLTAGE (V) Figure 10. On-State Voltage Figure 9. Pulse Trigger Current (V_{TM}) vs. On-State Current (I_{TM})

Typical Performance Characteristics (Continued)

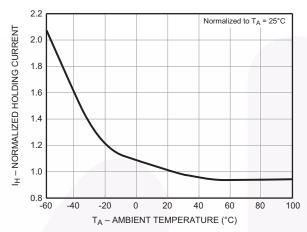


Figure 11. Normalized Holding Current (I_H) vs. Ambient Temperature (T_A)

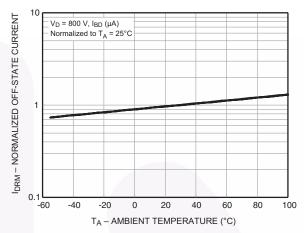


Figure 12. Normalized Off-State Current (IDRM) vs. Ambient Temperature (T_A)

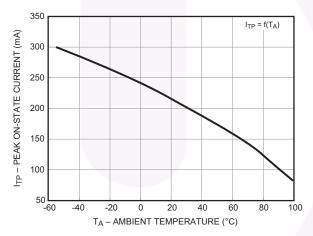
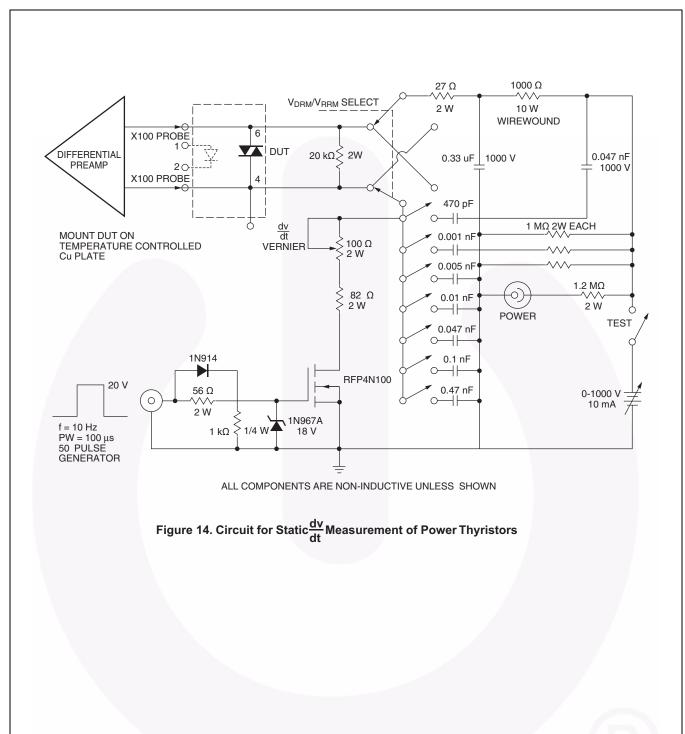
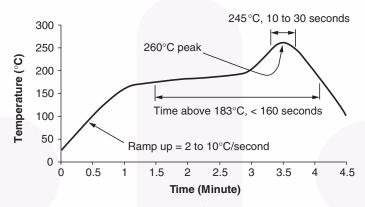


Figure 13. Current Reduction



Reflow Profile



- Peak reflow temperature: 260°C (package surface temperature)
 Time of temperature higher than 183°C for 160 seconds or less
- One time soldering reflow is recommended

Figure 15. Reflow Profile

Ordering Information

Part Number	Package	Packing Method
FOD420	DIP 6-Pin	Tube (50 Units)
FOD420S	SMT 6-Pin (Lead Bend)	Tube (50 Units)
FOD420SD	SMT 6-Pin (Lead Bend)	Tape and Reel (1000 Units)
FOD420V	DIP 6-Pin, DIN EN/IEC60747-5-5 Option	Tube (50 Units)
FOD420SV	SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option	Tube (50 Units)
FOD420SDV	SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option	Tape and Reel (1000 Units)
FOD420TV	DIP 6-Pin, 0.4" Lead Spacing, DIN EN/IEC60747-5-5 Option	Tube (50 Units)

Note:

6. The product orderable part number system listed in this table also applies to the FOD4208, FOD4216, and FOD4218product families.

Marking Information

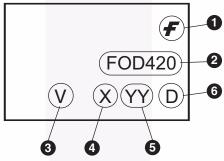
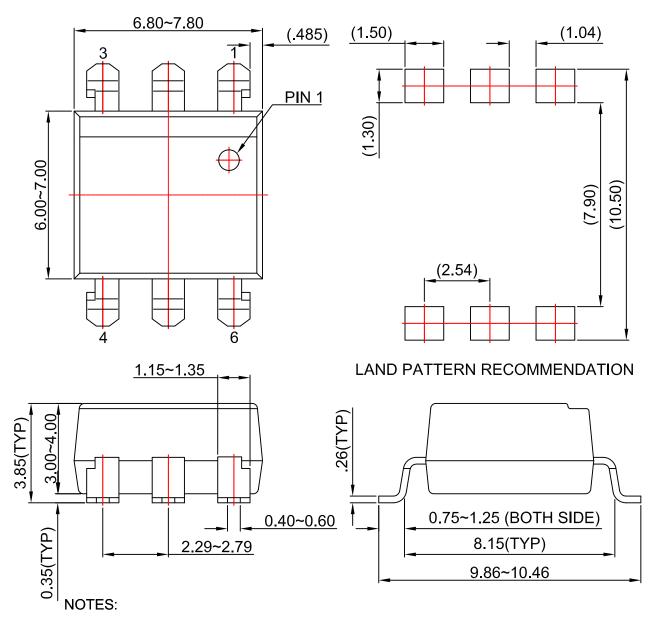


Figure 16. Top Mark

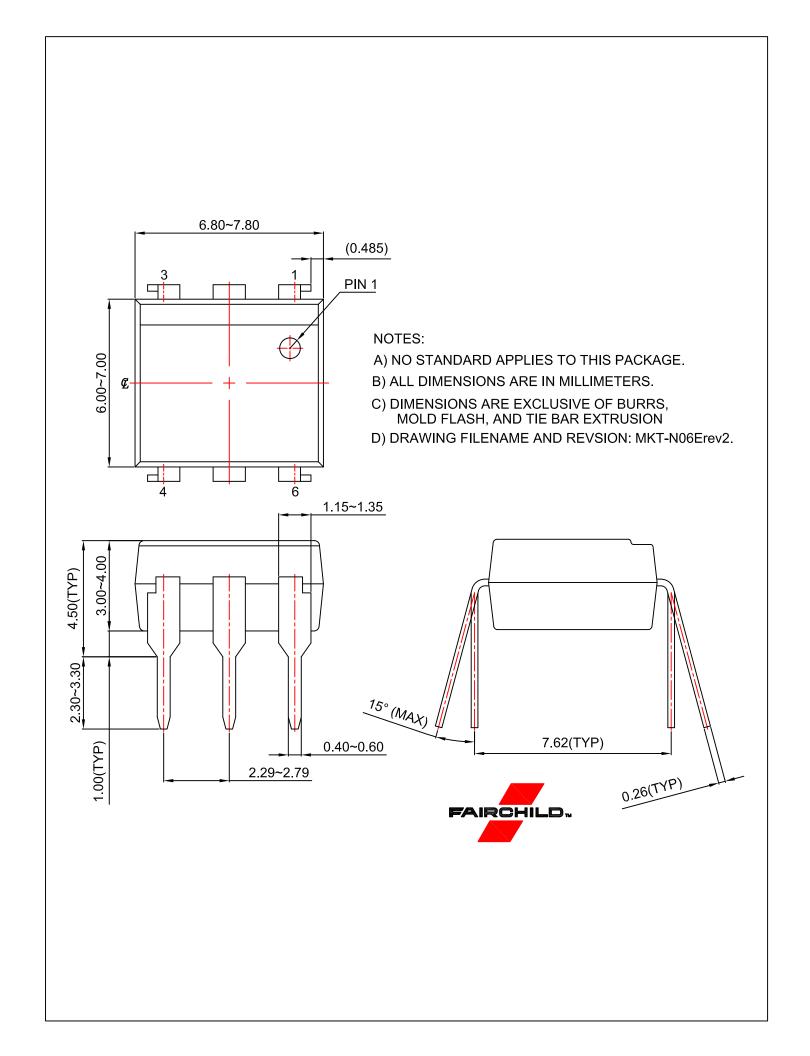
Table 1. Top Mark Definitions

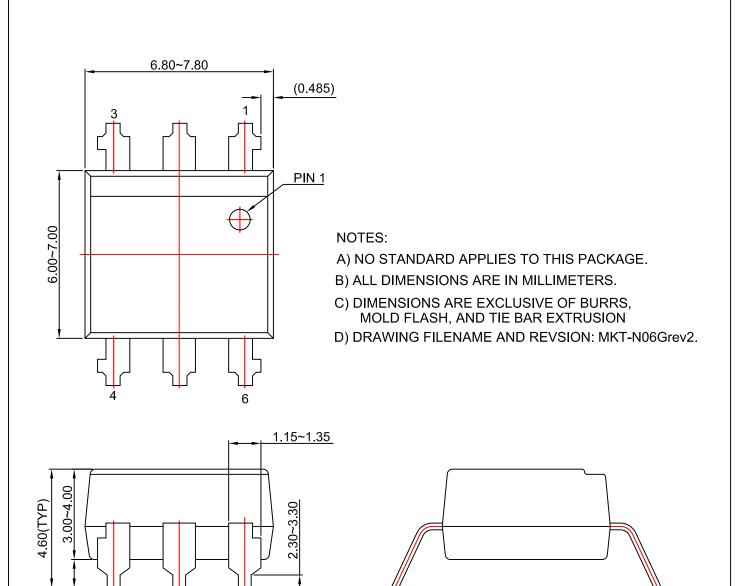
1	Fairchild Logo
2	Device Number
3	VDE mark. DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
4	One-Digit Year Code, e.g., "6"
5	Digit Work Week, Ranging from "01" to "53"
6	Assembly Package Code



- A) NO STANDARD APPLIES TO THIS PACKAGE.
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- D) DRAWING FILENAME AND REVSION: MKT-N06rev2.







15.00°(MAX)

0.40~0.60

2.29~2.79

10.16(TYP)

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